# VS-60EPU06HN3, VS-60APU06HN3

**Vishay Semiconductors** 

AUTOMOTIVE

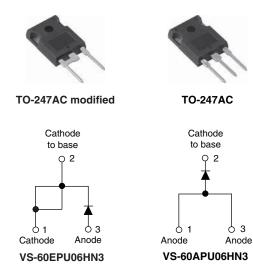
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RoHS

COMPLIANT

HALOGEN

# Ultrafast Soft Recovery Diode, 60 A FRED Pt®



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PRODUCT SUMMARY								
Package	TO-247AC modified (2 pins), TO-247AC							
IF(AV)	60 A							
V <sub>R</sub>	600 V							
V <sub>F</sub> at I <sub>F</sub>	1.11 V							
t <sub>rr</sub> typ.	See Recovery table							
T <sub>J</sub> max.	175 °C							
Diode variation	Single die							

### **FEATURES**

- Ultrafast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- AEC-Q101 qualified, meets JESD 201 class 1A whisker test

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

### **DESCRIPTION / APPLICATIONS**

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems.

The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS						
Cathode to anode voltage	V <sub>R</sub>		600	V						
Continuous forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 116 °C	60							
Single pulse forward current	I <sub>FSM</sub>	T <sub>C</sub> = 25 °C	600	А						
Maximum repetitive forward current	I <sub>FRM</sub>	Square wave, 20 kHz	120							
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C						

ELECTRICAL SPECIFICATIONS (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-			
	V <sub>F</sub>	I <sub>F</sub> = 60 A	-	1.35	1.68	V		
Forward voltage		I <sub>F</sub> = 60 A, T <sub>J</sub> = 125 °C	-	1.20	1.42			
		$I_F = 60 \text{ A},  \text{T}_\text{J} = 175 \ ^\circ\text{C}$	-	1.11	1.30			
Reverse leakage current	I <sub>R</sub>	$V_{\rm R} = V_{\rm R}$ rated	-	-	50			
		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA		
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	39	-	pF		

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1

Document Number: 93806

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 20$	00 A/µs, V <sub>R</sub> = 30 V	-	34	45			
	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	81	-	ns		
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 60 A dI <sub>F</sub> /dt = 200 A/µs	-	164	-			
Dook rooovon, ourront	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	7.4	-	А		
Peak recovery current		T <sub>J</sub> = 125 °C	$V_{\rm B} = 200 \text{ V}$	-	17.0	-	A		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C	VH - 200 V	-	300	-	nC		
		T <sub>J</sub> = 125 °C		-	1394	-			

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	0.63	к/W			
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.2	-	- r./ vv			
Weight			-	5.5	-	g			
weight			-	0.2	-	oz.			
Mounting torque			1.2 (10)	-	2.4 (20)	N ⋅ m (lbf ⋅ in)			
		Case style TO-247AC modified	60EPU06H						
Marking device		Case style TO-247AC		60APU06H					

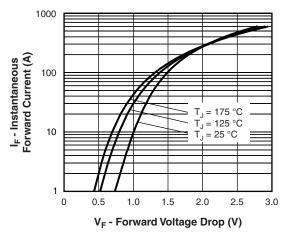
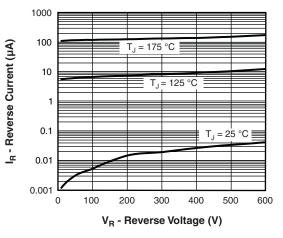
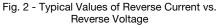


Fig. 1 - Typical Forward Voltage Drop Characteristics







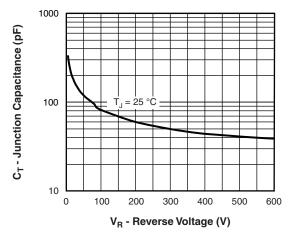


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

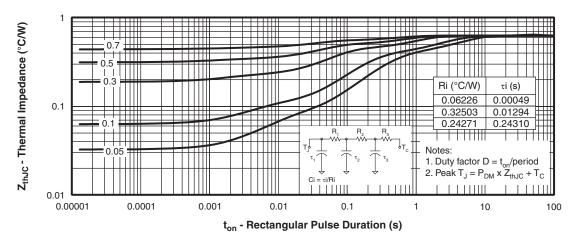
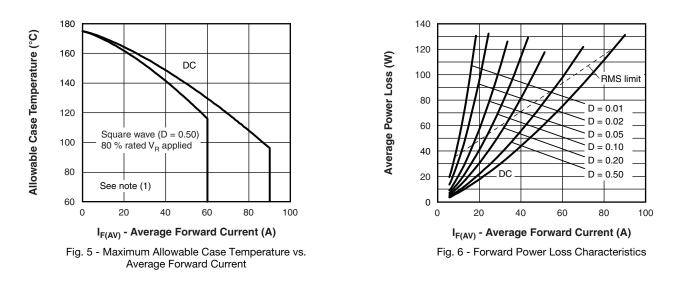


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



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Т

100

dl<sub>F</sub>/dt (A/µs)

Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

T<sub>.1</sub> = 125 °C

I<sub>F</sub> = 30 A

. I<sub>F</sub> = 60 A

T<sub>J</sub> = 25 °C

3000

2500

2000

1500

1000

500

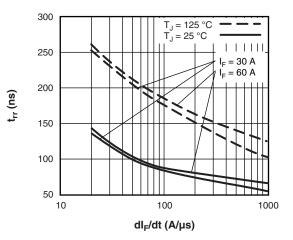
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10

Q<sub>rr</sub> (nC)

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1000



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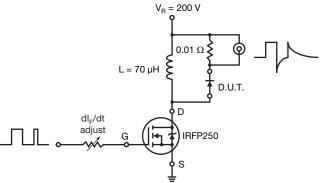
Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

#### Note

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<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 



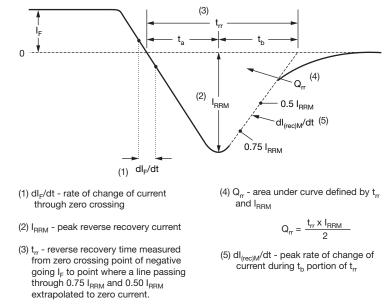
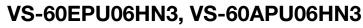


Fig. 10 - Reverse Recovery Waveform and Definitions

Ås.
ੁਂਛ Fig. 9 - Reverse Recovery Parameter Test Circuit
$(3)$ $t_{r}$ $t_{a}$ $t_{b}$ $(2)$ $l_{RRM}$ $(2)$ $l_{RRM}$ $dl_{(rec)M}/dt$ $(5)$ $0.75 l_{RRM}$
(1) dl <sub>F</sub> /dt

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### **ORDERING INFORMATION TABLE**

www.vishay.com

VISHAY

Device code	VS-	60	Е	Р	U	06	н	N3
		2	3	4	5	6	7	8
	1 .	- Vis	hay Sen	nicondu	ctors pro	oduct		
	2	- Cur	rent rati	ing (60 =	= 60 A)			
	3	- Circ	cuit conf	figuratio	n:			
			= single	e diode e diode,	3 nine			
	4		•	7AC (mc	•			
	5			st recove				
	6			ing (06 =	,	)		
			0	101 qua	,	/		
				-				
	8			ntal digit				
		N3	= halog	en-free,	RoHS-	complia	nt and f	totally le

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-60EPU06HN3	25	500	Antistatic plastic tube					
VS-60APU06HN3	25	500	Antistatic plastic tube					

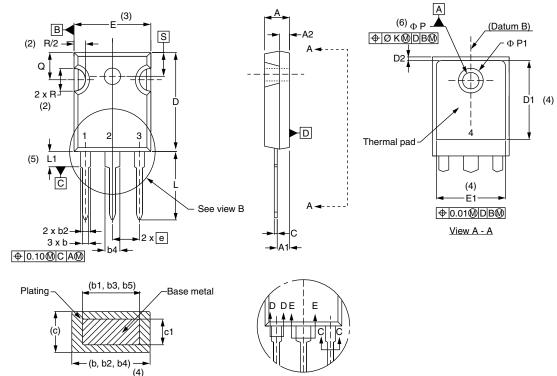
LINKS TO RELATED DOCUMENTS								
Dimensions	TO-247AC modified	www.vishay.com/doc?95253						
Dimensions	TO-247AC	www.vishay.com/doc?95223						
Part marking information	TO-247AC modified	www.vishay.com/doc?95442						
	TO-247AC	www.vishay.com/doc?95007						
SPICE model		www.vishay.com/doc?95545						





**TO-247AC** 

### **DIMENSIONS** in millimeters and inches



Section C - C, D - D, E - E



SYMBOL	MILLIMETERS		INCHES		INCHES NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.65	5.31	0.183	0.209			D2	0.51	1.30	0.020	0.051	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.50	2.49	0.059	0.098			E1	13.46	-	0.530	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	5 BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0	010	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			ØΡ	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133			Ø P1	-	6.98	-	0.275	
с	0.38	0.89	0.015	0.035			Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033			R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3	]	S	5.51 BSC		0.217	' BSC	
D1	13.08	-	0.515	-	4							

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

- <sup>(4)</sup> Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

 $^{(7)}$  Outline conforms to JEDEC  $^{\tiny (\! R \!)}$  outline TO-247 with exception of dimension c

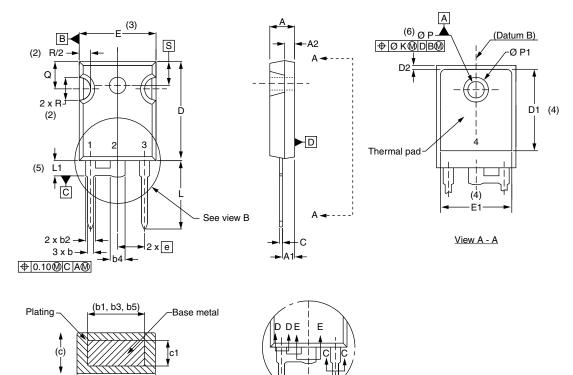
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# TO-247AC modified

### **DIMENSIONS** in millimeters and inches



(4) Section C - C, D - D, E - E

(b, b2, b4)

### View B

SYMBOL	MILLIMETERS		INCHES		NOTES		SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
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A1	2.21	2.59	0.087	0.102			Е	15.29	15.87	0.602	0.625	3
A2	1.50	2.49	0.059	0.098			E1	13.46	-	0.530	-	
b	0.99	1.40	0.039	0.055			е	5.46 BSC		0.215 BSC		
b1	0.99	1.35	0.039	0.053			ØК	0.254		0.010		
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с	0.38	0.89	0.015	0.035			Q	5.31	5.69	0.209	0.224	
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D	19.71	20.70	0.776	0.815	3	]	S	5.51 BSC		0.217 BSC		
D1	13.08	-	0.515	-	4							

#### Notes

<sup>(1)</sup> Dimensioning and tolerance per ASME Y14.5M-1994

<sup>(2)</sup> Contour of slot optional

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<sup>(4)</sup> Thermal pad contour optional with dimensions D1 and E1

<sup>(5)</sup> Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension c

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